TS3DV642 1.8V互換の制御およびパワー・ダウン・モード搭載の12チャネル、1:2マルチプレクサ/デマルチプレクサ

1 特長

- スイッチ・タイプ: 2:1または1:2
- 動的特性
  - 差動帯域幅(-3dB)
    - ポートA: 6.9GHz (標準値)
    - ポートB: 7.5GHz (標準値)
  - クロストーク(1.7GHzにおいて): -40dB
  - 絶縁(1.7GHzにおいて): -23dB
  - 挿入損失(DC)
    - ポートA: -0.75dB
    - ポートB: -1.0dB
  - 反射損失(1.7GHzにおいて): -15.9dB
  - ペア内(ビット間)スキュー
    - ポートA: 2ps
    - ポートB: 6ps
  - R_{ON}
    - ポートA: 6.5Ω
    - ポートB: 8.2Ω
  - 1GHzにおけるC_{ON}: 0.5 pF (標準値)
- V_{CC}範囲: 2.6V～4.5V
- I/O電圧範囲: 0V～5V
- 特殊機能
  - I_{OFF}保護により、パワー・ダウン状態(V_{CC} = 0V)での電流リークを防止
- ESD性能
  - 2kV人体モデル(A114B、Class II)
  - 1kV荷電デバイス・モデル(C101)
- 42ピンのWQFNパッケージ(9mm×3.5mm、0.5mmピッチ)

2 アプリケーション

- HDMI 2.0で最高60Hzの4k2kをサポート
- DVI 1.0信号スイッチング
- DisplayPort 1.4信号スイッチング
- 汎用TMDS信号スイッチング
- 汎用LVDS信号スイッチング
- 汎用高速信号スイッチング

3 概要

TS3DV642は、12チャネル、1:2または2:1の双方向マルチプレクサ/デマルチプレクサです。TS3DV642は2.6V～4.5Vの電源電圧で動作するため、バッテリ駆動のアプリケーションに好適です。オン抵抗(R_{ON})がフラットで小さく、I/O容量も小さいため、最高7.5GHzの標準帯域幅を実現できます。このデバイスは、HDMIおよびDisplayPortアプリケーションに必要な高い帯域幅を提供できます。

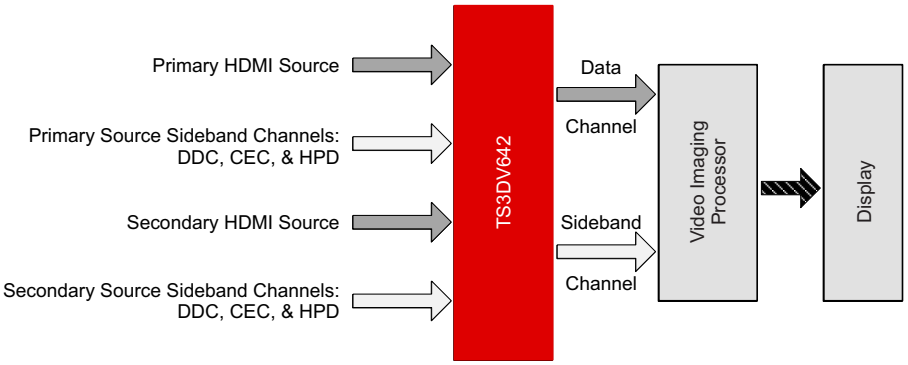
TS3DV642にはパワー・ダウン・モードがあり、このモードではすべてのチャネルがHi-Zになり、デバイスは最小の電力で動作します。

製品情報(1)

型番	パッケージ	本体サイズ(公称)
TS3DV642	WQFN (42)	9.00mm×3.50mm

(1) 利用可能なすべてのパッケージについては、このデータシートの末尾にある注文情報を参照してください。

概略回路図



目次

4 改訂履歴

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Revision E (June 2017) から **Revision F** に変更 **Page**

- Changed Figure 27, removed capacitors ... 21

Revision D (December 2015) から **Revision E** に変更 **Page**

- 「アプリケーション」の「DisplayPort 1.2a信号スイッチング」を「DisplayPort 1.4信号スイッチング」に ... 1
- Added Test Condition of 4.05 GHZ at –35 dB to Xtalk in the *Dynamic Characteristics* table ... 8
- Added Test Condition of 4.05 GHZ at –25 dB to OISO in the *Dynamic Characteristics* table ... 8

Revision C (November 2014) から **Revision D** に変更 **Page**

- Changed the storage temperature to the *Absolute Maximum Ratings* table ... 6

Revision B (August 2013) から **Revision C** に変更 **Page**

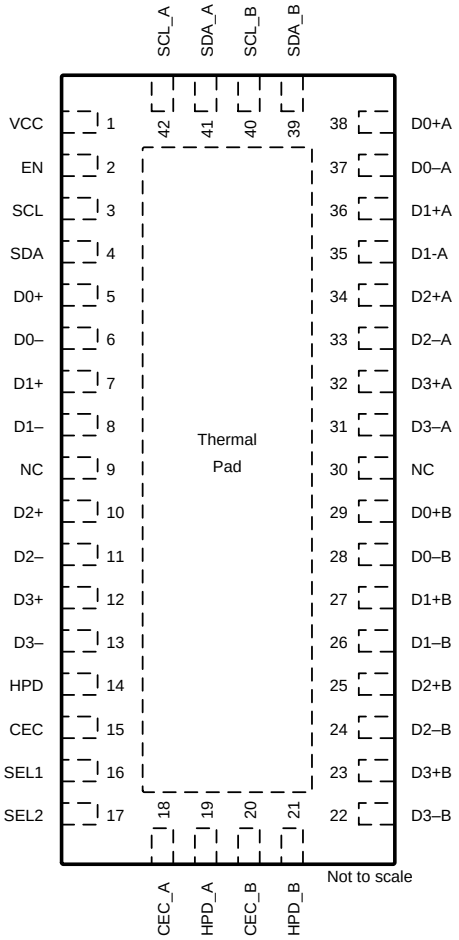
- 「取り扱い定格」表、「機能説明」セクション、「デバイスの機能モード」セクション、「アプリケーションと実装」セクション、「電源に関する推奨事項」セクション、「レイアウト」セクション、「デバイスおよびドキュメントのサポート」セクション、「メカニカル、パッケージ、および注文情報」セクション 追加 ... 1
- Deleted row from ABS MAX table: Package thermal impedance ... 6
- Added the Handling Ratings table, deleted the T_{stg} row Absolute Maximum ratings table and added to Handling Ratings table. ... 6

Revision A (July 2013) から Revision B に変更 **Page**

- 「アプリケーション」の「HDMI 1.4/DVI 1.0信号スイッチング」を「HDMI 1.4bで最高30Hzの4k2kをサポート」に 変更 1
- 「アプリケーション」に「DVI 1.0信号スイッチング」を 追加 1
- 「アプリケーション」の「DisplayPort 1.2信号スイッチング」を「DisplayPort 1.2a信号スイッチング」に 変更 1
- Added Eye Pattern and Time Interval Error Histogram graphics, Figure 10 to Figure 13 10

5 Pin Configuration and Functions

RUA Package
42 Pin WQFN With Exposed Thermal Pad
Top View



Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.		
VCC	1	Power	Supply Voltage
SEL1	16	I	Select Input 1
SEL2	17	I	Select Input 2
EN	2	I	Output Enable
D0+A	38	I/O	Port A, Channel 0, +ve signal
D0–A	37	I/O	Port A, Channel 0, –ve signal
D1+A	36	I/O	Port A, Channel 1, +ve signal
D1-A	35	I/O	Port A, Channel 1, –ve signal
D2+A	34	I/O	Port A, Channel 2, +ve signal
D2–A	33	I/O	Port A, Channel 2,–ve signal
D3+A	32	I/O	Port A, Channel 3, +ve signal
D3–A	31	I/O	Port A, Channel 3, –ve signal
SCL_A	42	I/O	Port A, DDC Clock
SDA_A	41	I/O	Port A, DDC Data

Pin Functions (continued)

PIN		TYPE	DESCRIPTION
NAME	NO.		
HPD_A	19	I/O	Port A, Hot Plug Detects
CEC_A	18	I/O	Port A, Consumer Electronics Control
D0+B	29	I/O	Port B, Channel 0, +ve signal
D0–B	28	I/O	Port B, Channel 0, –ve signal
D1+B	27	I/O	Port B, Channel 1, +ve signal
D1–B	26	I/O	Port B, Channel 1, –ve signal
D2+B	25	I/O	Port B, Channel 2, +ve signal
D2–B	24	I/O	Port B, Channel 2,–ve signal
D3+B	23	I/O	Port B, Channel 3, +ve signal
D3–B	22	I/O	Port B, Channel 3, –ve signal
SCL_B	40	I/O	Port B, DDC Clock
SDA_B	39	I/O	Port B, DDC Data
HPD_B	21	I/O	Port B, Hot Plug Detects
CEC_B	20	I/O	Port B, Consumer Electronics Control
D0+	5	I/O	Common Port, Channel 0, +ve signal
D0–	6	I/O	Common Port, Channel 0, –ve signal
D1+	7	I/O	Common Port, Channel 1, +ve signal
D1–	8	I/O	Common Port, Channel 1, –ve signal
D2+	10	I/O	Common Port, Channel 2, +ve signal
D2–	11	I/O	Common Port, Channel 2, –ve signal
D3+	12	I/O	Common Port, Channel 3, +ve signal
D3–	13	I/O	Common Port, Channel 3,–ve signal
SCL	3	I/O	Common Port, DDC Clock
SDA	4	I/O	Common Port, DDC Data
HPD	14	I/O	Common Port, Hot Plug Detects
CEC	15	I/O	Common Port, Consumer Electronics Control
NC	9, 30	NC	No Connect
GND	PowerPad	GND	Ground

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		–0.5	5.5	V
$V_{I/O}$	Analog voltage range(2)(3)(4)	All I/O	–0.5	5.5	V
V_{IN}	Digital input voltage range(2)(3)	SEL1, SEL2, EN	–0.5	5.5	V
$I_{I/OK}$	Analog port diode current	$V_{I/O}$ < 0		–50	mA
I_{IK}	Digital input clamp current	V_{IN} < 0		–50	mA
$I_{I/O}$	On-state switch current(5)		–128	128	mA
T_{stg}	Storage temperature range		–65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltages are with respect to ground, unless otherwise specified.
(3) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
(4) V_I and V_O are used to denote specific conditions for $V_{I/O}$.
(5) I_I and I_O are used to denote specific conditions for $I_{I/O}$.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, (1)	±2000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101, (2)	±1000	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
V_{CC}	Supply voltage	2.6	4.5	V
$V_{I/O}$	Input/Output voltage	0	5.5	V
T_A	Operating free-air temperature	–40	85	°C

(1) All unused control inputs of the device must be held at VDD or GND to ensure proper device operation. Refer to the *TI application report, Implications of Slow or Floating CMOS Inputs,* literature number SCBA004.

6.4 Thermal Information

THERMAL METRIC(1)		TS3DV642 RUA 42 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	31.5	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	16.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	5.5	°C/W
ψ_{JT}	Junction-to-top characterization parameter	0.2	°C/W
ψ_{JB}	Junction-to-board characterization parameter	5.4	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	2.0	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER			TEST CONDITIONS(1)	MIN	TYP(2)	MAX	UNIT
PORT A							
R_{ON}	ON-state resistance	D0 to D3	V_{CC} = 3 V, 1.5 V ≤ $V_{I/O}$ ≤ V_{CC}, $I_{I/O}$ = –40 mA		6.5	9.5	Ω
		SCL, SDA, HPD, CEC			6	9.5	Ω
$R_{ON(flat)}$(3)	ON-state resistance flatness	All I/O	V_{CC} = 3 V, $V_{I/O}$ = 1.5 V and V_{CC}, $I_{I/O}$ = –40 mA		1.5		Ω
ΔR_{ON}(4)	On-state resistance match between high-speed channels	D0 to D3	VCC = 3 V, 1.5 V ≤ VI/O ≤ V_{CC}, $I_{I/O}$ = –40 mA		0.4	1	Ω
I_{OFF}	Leakage under power off	All outputs	V_{CC} = 0 V, $V_{I/O}$ = 0 to 3.6 V, V_{IN} = 0 V to 5.5 V			±10	µA
PORT B							
R_{ON}	ON-state resistance	D0 to D3	V_{CC} = 3 V, 1.5 V ≤ $V_{I/O}$ ≤ V_{CC}, II/O = –40 mA		8.2	10.5	Ω
		SCL, SDA, HPD, CEC			6	9.5	Ω
$R_{ON(flat)}$(3)	ON-state resistance flatness	All I/O	V_{CC} = 3 V, $V_{I/O}$ = 1.5 V and V_{CC}, $I_{I/O}$ = –40 mA		1.5		Ω
ΔR_{ON}(4)	On-state resistance match between high-speed channels	D0 to D3	V_{CC} = 3 V, 1.5 V ≤ $V_{I/O}$ ≤ V_{CC}, $I_{I/O}$ = –40 mA		0.4	1	Ω
I_{OFF}	Leakage under power off	All outputs	V_{CC} = 0 V, $V_{I/O}$ = 0 V to 3.6 V, V_{IN} = V to 5.5 V			±10	µA
DIGITAL INPUTS (SEL1, SEL2, EN)							
V_{IH}	High-level control input voltage	SEL1, SEL2, EN		1.4			V
V_{IL}	Low-level control input voltage	SEL1, SEL2, EN				0.5	V
I_{IH}	Digital input high leakage current	SEL1, SEL2, EN	V_{CC} = 3.6 V , V_{IN} = V_{DD}			±10	µA
I_{IL}	Digital input low leakage current	SEL1, SEL2, EN	V_{CC} = 3.6 V, V_{IN} = GND			±10	µA
SUPPLY							
I_{CC}	VCC supply current		V_{CC} = 3.6 V, $I_{I/O}$ = 0, Normal Operation Mode, EN = H		50		µA
I_{CC}, PD	VCC supply current in power-down mode		V_{CC} = 3.6 V, $I_{I/O}$ = 0, EN = L		6		µA

(1) V_I, V_O, I_I, and I_O refer to I/O pins, V_{IN} refers to the control inputs.
(2) All typical values are at V_{CC} = 3.3 V (unless otherwise noted), T_A = 25°C.
(3) $R_{ON(FLAT)}$ is the difference of R_{ON} in a given channel at specified voltages.
(4) ΔR_{ON} is the difference of RON from center port to any other ports.

6.6 Dynamic Characteristics

Over recommended operation free-air temperature range, V_{CC} = 3.3V ± 0.3V (unless otherwise noted)

PARAMETER			TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
C_{IN}	Digital input capacitance		f = 1 MHz, V_{IN} = 0 V		6		pF
Coff	Switch OFF capacitance		f = 1 GHz, $V_{I/O}$ = 0 V, Output is open, Switch is OFF		0.3		pF
Con	Switch ON capacitance		f = 1 GHz, $V_{I/O}$ = 0 V, Output is open, Switch is ON		0.5		pF
Xtalk	Differential Crosstalk		R_L = 50 Ω at 1.7 GHz (See Figure 17)		–40		dB
			R_L = 50 Ω at 2.7 GHz (See Figure 17)		–40		
			R_L = 50 Ω at 4.05 GHz (See Figure 17)		–35		
OISO	Differential Off Isolation		R_L = 50 Ω at 1.7 GHz (See Figure 18)		–23		dB
			R_L = 50 Ω at 2.7 GHz (See Figure 18)		–28		
			R_L = 50 Ω at 4.05 GHz (See Figure 18)		–25		
IL	Insertion Loss		Port A at DC		–0.75		dB
			Port B at DC		–1		
BW	Differential Bandwidth (–3 dB)	Port A	R_L = 50 Ω, All channels (See Figure 19)		6.9		GHz
		Port B	R_L = 50 Ω, All channels (See Figure 19)		7.5		

(1) All Typical Values are at V_{CC} = 3.3 V (unless otherwise noted), T_A = 25°C.

6.7 Switching Characteristics

over recommended operation free-air temperature range, V_{CC} = 3.3 V± 0.3 V (unless otherwise noted)

PARAMETER				TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
t_{ON}(2)	Switch turn-on time		All I/O	See Figure 14			100	µs
t_{SWITCH}(3)	Switching time between channels		All I/O	See Figure 15		20		µs
t_{pd}	Propagation Delay	Port A	D0 to D3	See Figure 16		30		ps
			SCL, SDA, HPD, CEC			30		
		Port B	D0 to D3			40		
			SCL, SDA, HPD, CEC			30		
t_{SKEW}	Inter-pair Skew	Port A	D0 to D3	Between +ve and –ve signals of each Channel		2		ps
		Port B				2		
	Intra-pair Skew	Port A		Between Channel 0, 1, 2, or 3		2		
		Port B				6		

(1) All typical values are at V_{CC} = 3.3 V (unless otherwise noted), T_A = 25°C.
(2) t_{ON} is the time it takes the output to recover after enabling switches
(3) t_{SWITCH} is the time it takes for the output to recover after the state is changed

6.8 Typical Characteristics

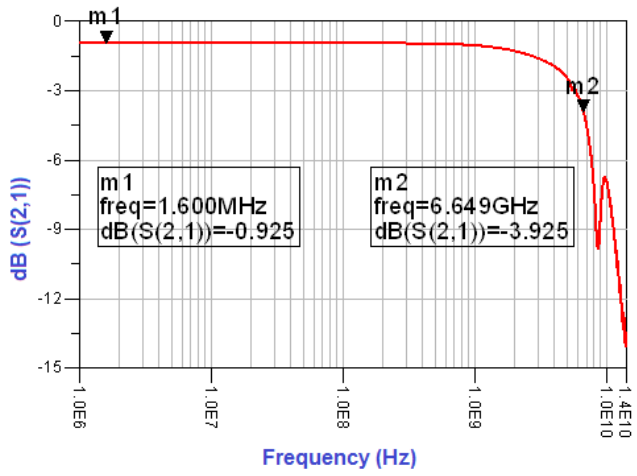


Figure 1. Differential S21 vs Frequency for Port A

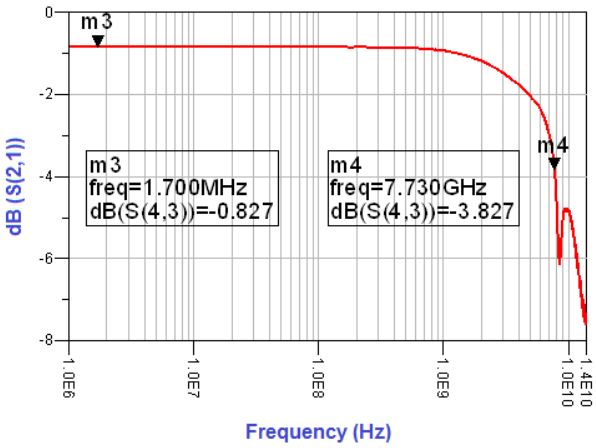


Figure 2. Differential S21 vs Frequency for Port B

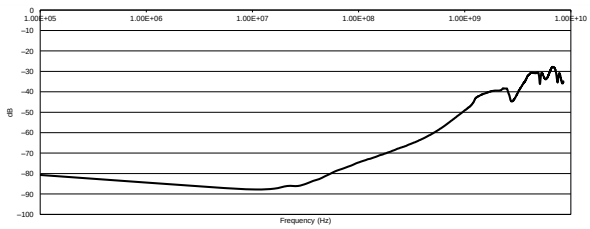


Figure 3. XTALK Port A

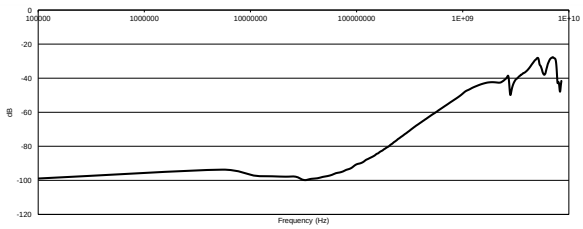


Figure 4. XTALK Port B

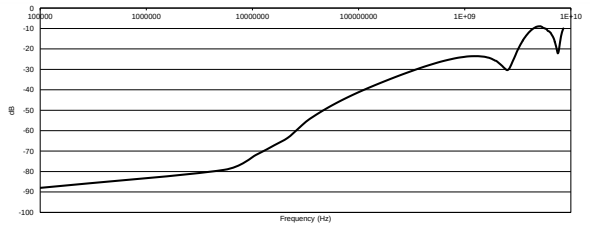


Figure 5. Off-State Isolation (OISO) for Port A

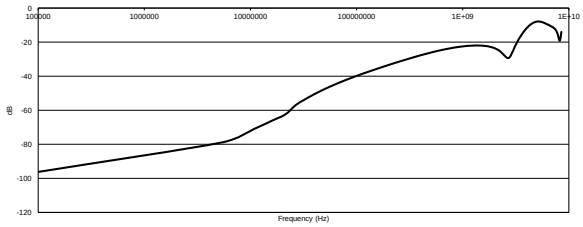


Figure 6. Off-State Isolation (OISO) for Port B

Typical Characteristics (continued)

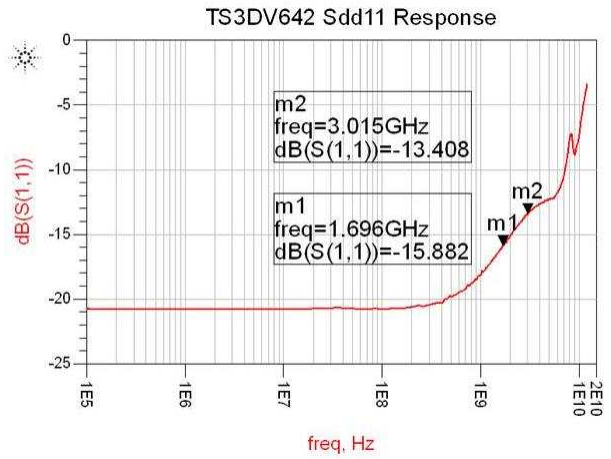


Figure 7. Return Loss (S11) Characteristics of TS3DV642

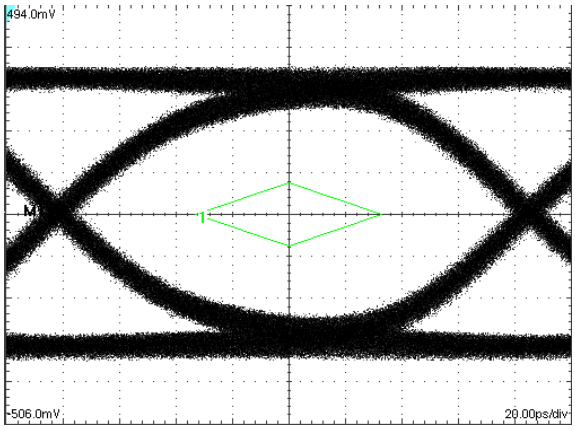


Figure 8. Eye Pattern: 6.0 Gbps Port A, D1+ to D1+A, D1- to D1-A (Only One Channel Measured at a Time)

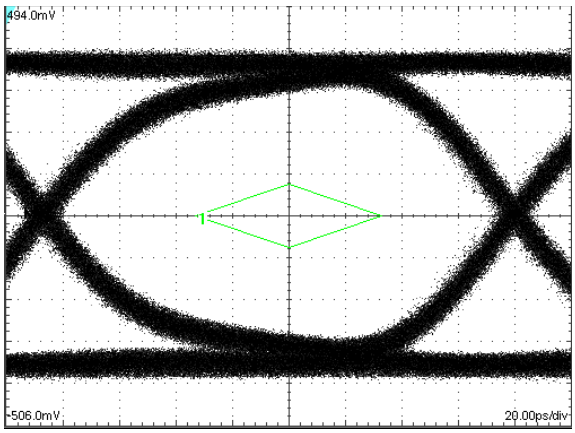


Figure 9. Eye Pattern: 6.0 Gbps, No Device Through Path (Only One Channel Measured at a Time)

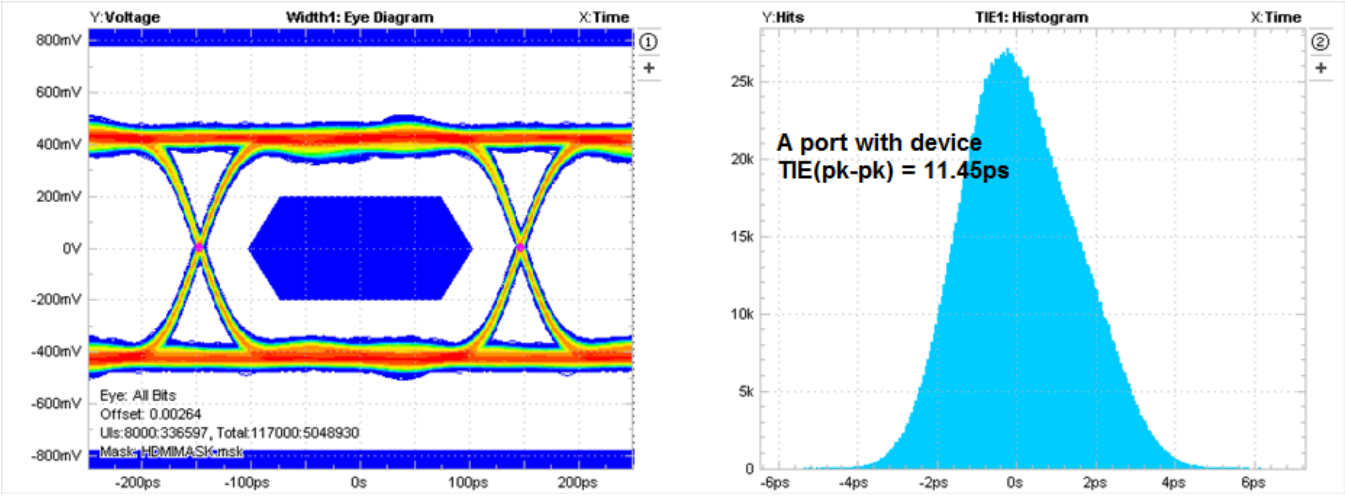


Figure 10. Eye Pattern and Time Interval Error Histogram: 3.4 Gbps Port A, With Device

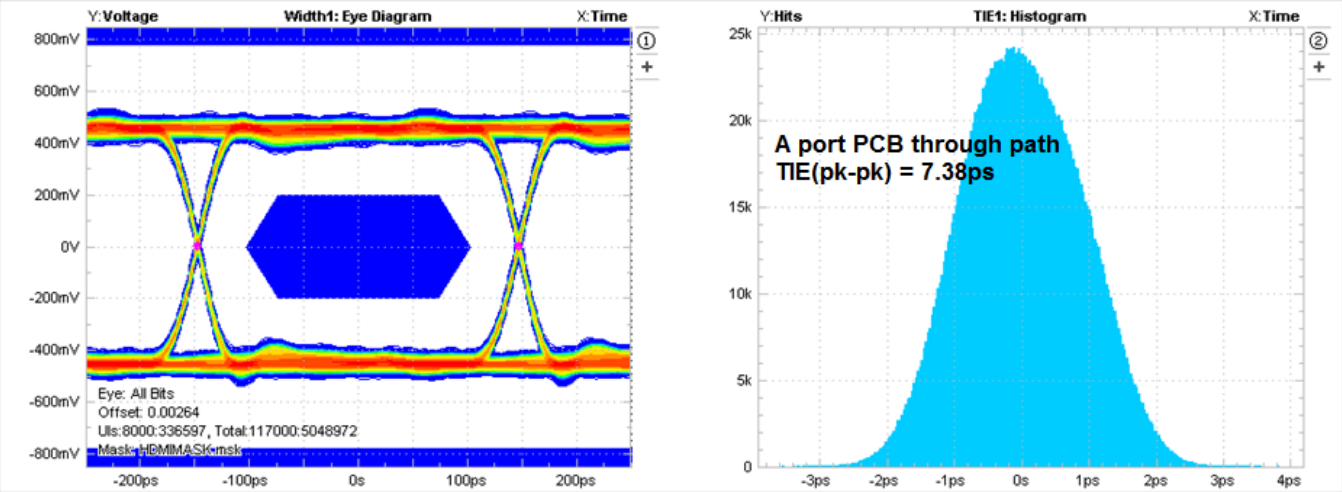


Figure 11. Eye Pattern and Time Interval Error Histogram: 3.4 Gbps, No Device Through Path

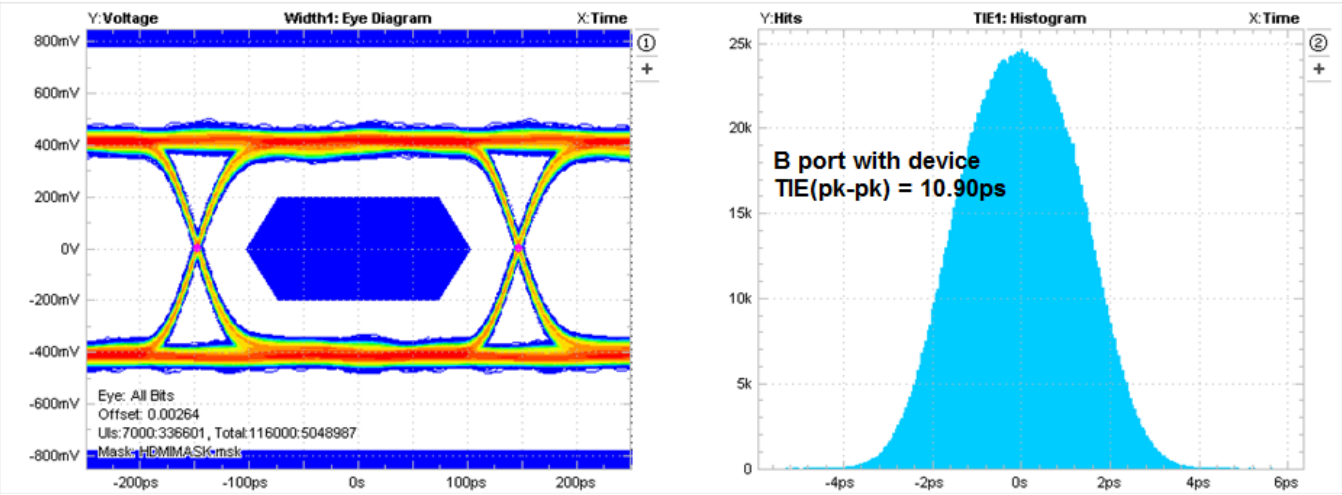


Figure 12. Eye Pattern and Time Interval Error Histogram: 3.4 Gbps Port B, With Device

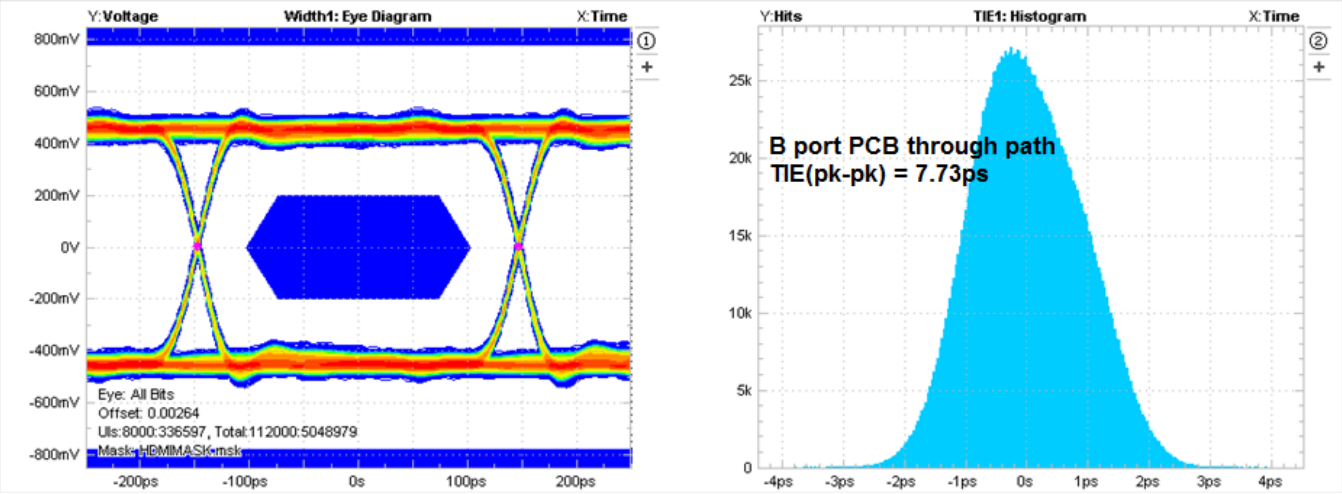
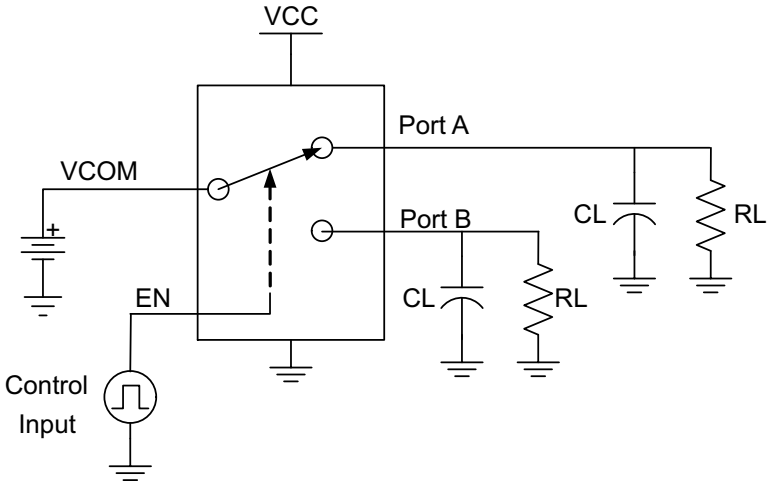


Figure 13. Eye Pattern and Time Interval Error Histogram: 3.4 Gbps Port B, No Device

7 Parameter Measurement Information



RL	CL	VCOM
50 Ω	4 pF	VCC

*CL includes probe, cable, and board capacitance

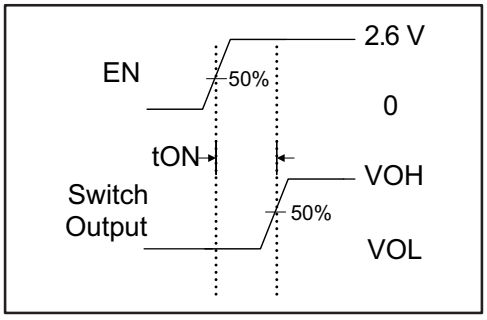
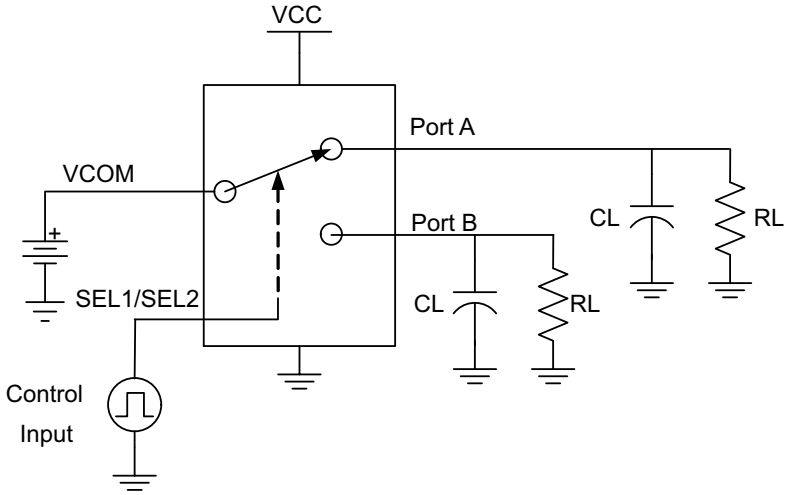


Figure 14. Switch Turn-On Time (t_{ON})



RL	CL	VCOM
50 Ω	4 pF	VCC

*CL includes probe, cable, and board capacitance

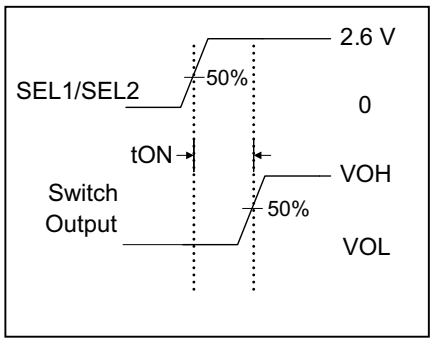
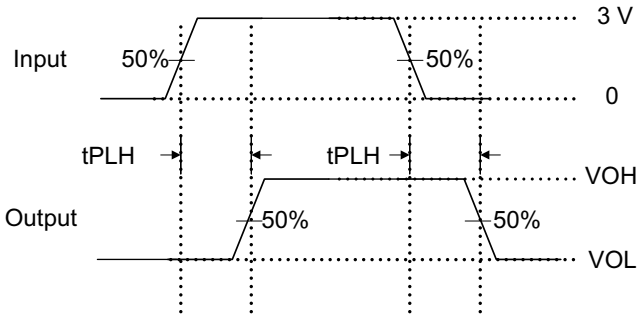


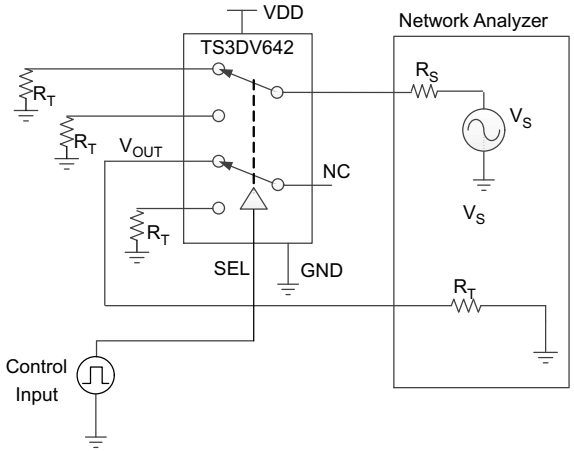
Figure 15. Switching Time Between Channels (t_{SWITCH})



$$tpd = (tPLH + tPLH) / 2$$

Figure 16. Propagation Delay (t_{pd})

Parameter Measurement Information (continued)

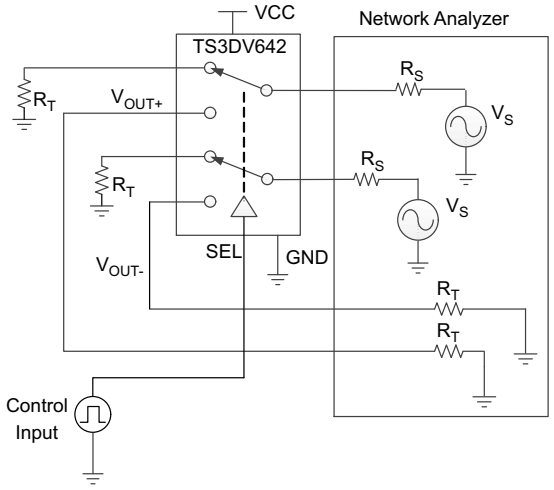


Channel ON

SEL = H or L
$R_S = R_T = 50\Omega$

V_S = -10dBm (200mV at 50Ω Load)
V_{DC_BIAS} = 1 V

Figure 17. Crosstalk (Xtalk)

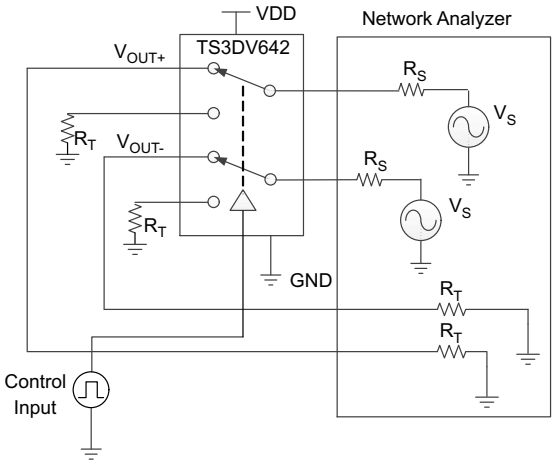


Channel OFF

SEL = H or L
$R_S = R_T = 50\Omega$

V_S = -10dBm (200mV at 50Ω Load)
V_{DC_BIAS} = 1 V

Figure 18. Differential Off-Isolation (OISO)



Channel ON

SEL = H or L
$R_S = R_T = 50\Omega$

V_S = -10dBm (200mV at 50Ω Load)
V_{DC_BIAS} = 1 V

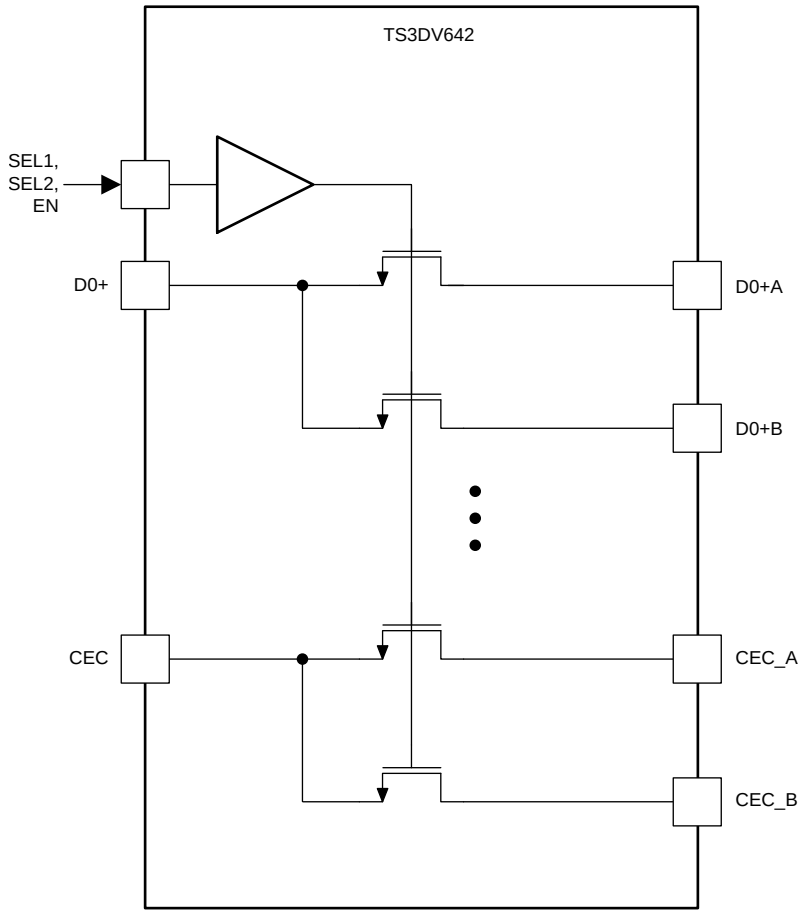
Figure 19. Differential Bandwidth (BW)

8 Detailed Description

8.1 Overview

TS3DV642 is a 12-channel 1:2 or 2:1 bidirectional multiplexer/demultiplexer. The TS3DV642 operates from a 2.6 to 4.5 V supply, making it suitable for battery-powered applications. It offers low and flat on-state resistance as well as low I/O capacitance which allows it to achieve a typical bandwidth of up to 7.5 GHz. The device provides the high bandwidth necessary for HDMI and DisplayPort applications.

8.2 Functional Block Diagram



8.3 Feature Description

The TS3DV642 is based on proprietary TI technology which uses FET switches driven by a high-voltage generated from an integrated charge-pump to achieve a low on-state resistance. TS3DV642 has 12-channel bidirectional switches with a high bandwidth (~ 7.5 GHz). TS3DV642 uses an extremely low power technology and uses only 50 µA I_{CC} in active mode. The device has integrated ESD that can support up to 2-kV Human-Body Model (HBM) and 1-kV Charge Device Model (CDM). TS3DV642 is offered in a 42-pin QFN package (9 mm x 3.5 mm) with 0.5 mm pitch. The device can support analog I/O signal in 0 to 5 V range. TS3DV642 also has a special feature that prevents the device from back-powering when the V_{CC} supply is not available and an analog signal is applied on the I/O pin. In this situation this special feature prevents leakage current in the device. The TS3DV642 is not designed for passing signals with negative swings; the high-speed signals need to be properly DC biased (usually ~1 V) before being passed to the TS3DV642. The differential S21 characteristics as a function of frequency for Port A and Port B are shown in Figure 1 and Figure 2, respectively. The figures show a differential bandwidth of 6.7 GHz and 7.7 GHz for Port A and Port B, respectively. The cross-talk (XTALK) characteristics as a function of frequency are shown in Figure 3 and Figure 4, respectively. The off-state isolation (OISO) characteristics for Port A and Port B are shown in Figure 5 and Figure 6, respectively. The return loss

Feature Description (continued)

characteristics (S11) are shown in Figure 7. The eye pattern and Time Interval Error (TIE) histogram at 3.4 Gbps (for HDMI 1.4 applications) with TS3DV642 in path for Port A is shown in Figure 10. The eye pattern and Time Interval Error (TIE) histogram at 3.4 Gbps through path (no TS3DV642) for Port A is shown in Figure 11. The eye pattern and Time Interval Error (TIE) histogram at 3.4 Gbps (for HDMI 1.4 applications) with TS3DV642 in path for Port B is shown in Figure 12. The eye pattern and Time Interval Error (TIE) histogram at 3.4 Gbps through path (no TS3DV642) for Port A is shown in Figure 13. The eye pattern at 6.0 Gbps (for HDMI 2.0 applications) with TS3DV642 in path for Port A is shown in Figure 8. The eye pattern at 6.0 Gbps (for HDMI 2.0 applications) through path (no TS3DV642) for Port A is shown in Figure 9. Note that the eye patterns are measured with only one channel on at a time.

8.4 Device Functional Modes

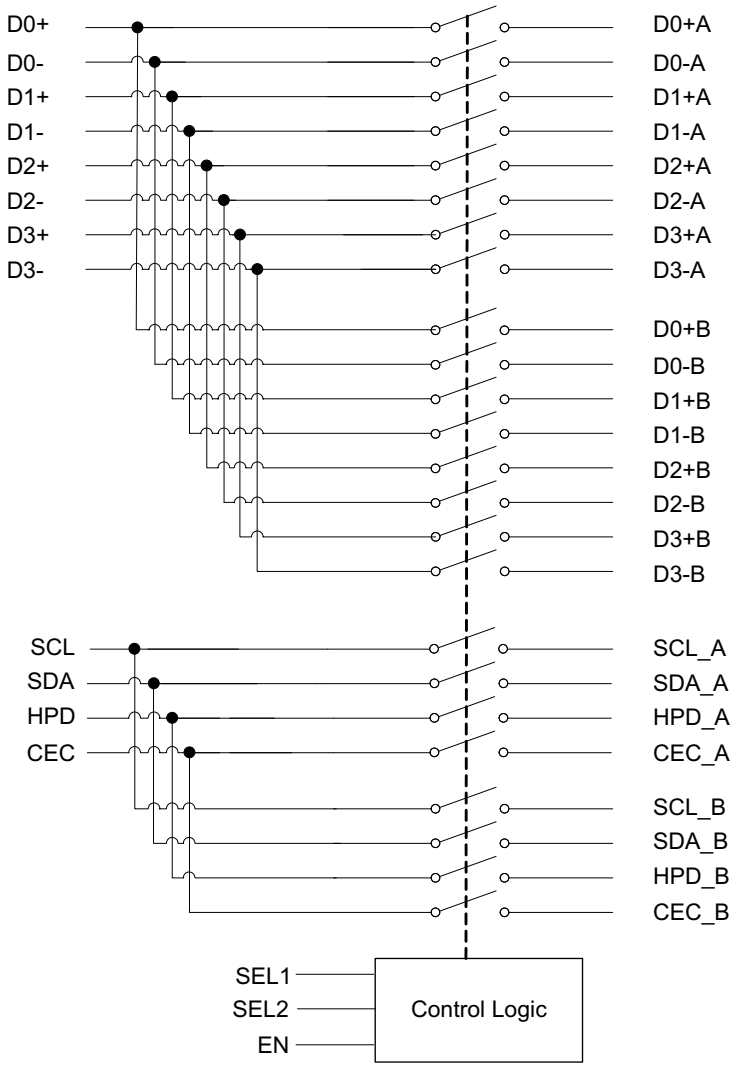


Figure 20. Logic Diagram

Device Functional Modes (continued)

Table 1 lists the device functions for the TS3DV642 device.

Table 1. Functional Table

EN	SEL1	SEL2	FUNCTION
L	X	X	Switch disabled. All channels are Hi-Z.
H	L	L	Channel D0+/D0– to D0+A/D0–A is ON. All the other channels (D1+/D1-, D2+/D2-, D3+/D3-, SCL, SDA, HPD, CEC) are Hi-Z.
H	L	H	Channel D0+/D0– to D0+B/D0–B is ON. All the other channels (D1+/D1-, D2+/D2-, D3+/D3-, SCL, SDA, HPD, CEC) are Hi-Z.
H	H	L	All A channels are enabled. All B channels are Hi-Z.
H	H	H	All B channels are enabled. All A channels are Hi-Z.

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

TS3DV642 can be used for two typical DisplayPort applications. Figure 21 describes a DisplayPort (DP) application where TS3DV642 is used to switch between two different graphic & memory controllers on a single DP connector. Figure 24 shows a docking application where TS3DV642 is used to switch signals from a single graphic and memory controller to a display port and docking station connector. Note that the TS3DV642 is not designed for passing signals with negative swings; the high-speed signals need to be properly DC biased (usually ~1 V from the graphic controller side) before being passed to the TS3DV642.

9.2 Typical Application

9.2.1 Display Port (DP) Application

Display port (DP) application with TS3DV642 used to switch between two different graphic & memory controllers on a single DP connector

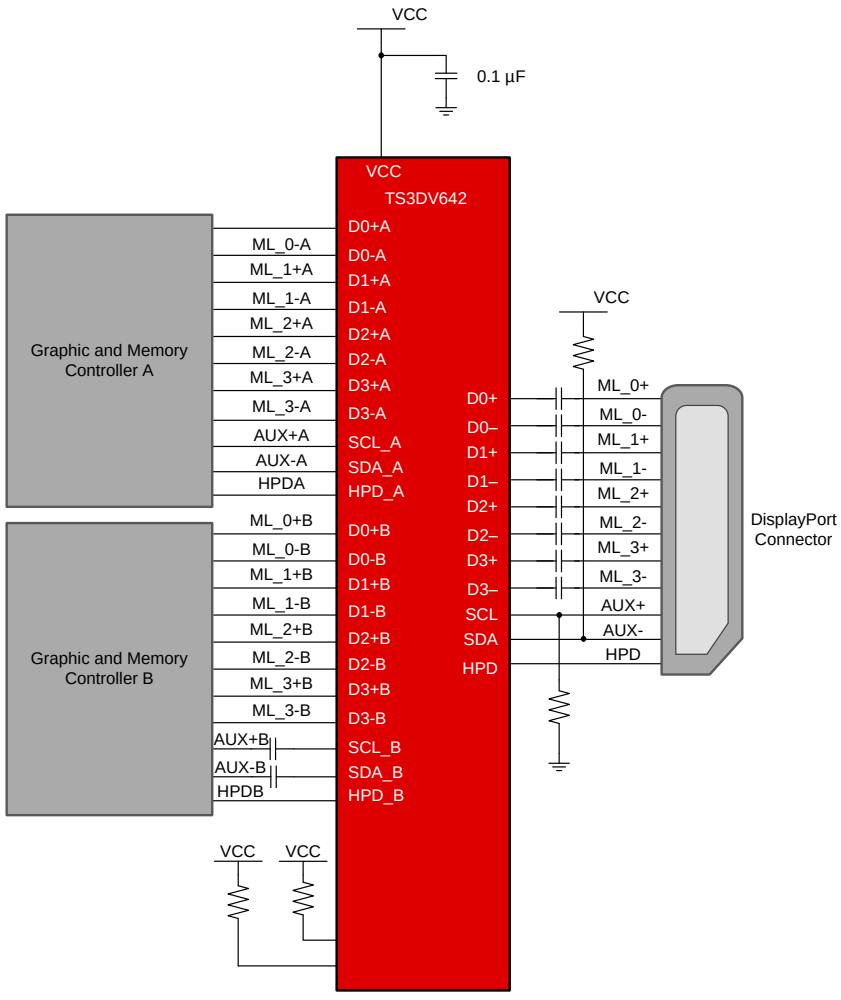


Figure 21. Display Port Schematic

Typical Application (continued)

9.2.1.1 Design Requirements

Table 2. Design parameters for Display Port application

Design parameter	Example value
V_{CC}	2.6 V to 4.5 V
VCC decoupling capacitor	0.1 µF
MainLink (ML) and AUX coupling capacitor	75 nF to 200 nF
AUX Pull-up / Pull-down resistors	10 kΩ to 100 kΩ
Pull-up / Pull-down resistors for SEL1 / SEL2 pins	10 kΩ

9.2.1.2 Detailed Design Procedure

The TS3DV642 is designed to operate with 2.6 V – 4.5 V power supply. The wide power supply range allows flexibility for battery powered applications. If a higher power supply is used in the system, a voltage regulator can be used to bring down the voltage to 2.6 V – 4.5 V range. Decoupling capacitors may be used to reduce noise and improve power supply integrity. AC coupling capacitors in 75 nF – 200 nF range must be placed on the MainLink (ML) and AUX lanes. In this particular application the AC coupling capacitors are shown on the connector side. The AC coupling capacitors may also be placed on the signal path on controller side. The AUX+ line must be pulled-down weakly through a resistor to ground and the AUX– line must be pulled-up weakly through a resistor to VCC.

9.2.1.3 Application Curves

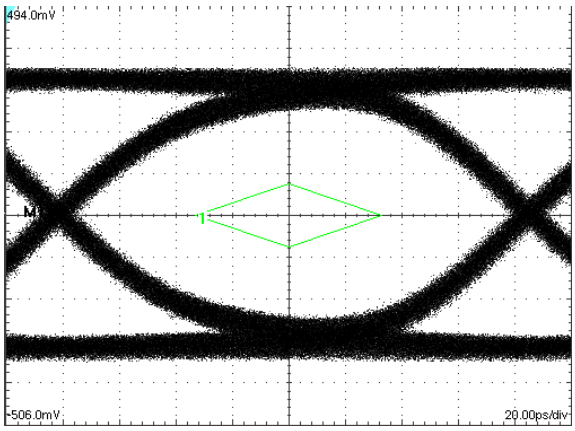


Figure 22. Eye Pattern: 6.0 Gbps Port A, D1+ to D1+A, D1- to D1-A (Only One Channel Measured at a Time)

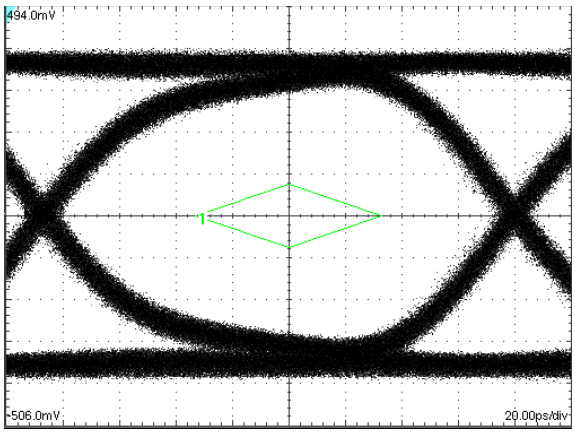


Figure 23. Eye Pattern: 6.0 Gbps, No Device Through Path (Only One Channel Measured at a Time)

9.2.2 Docking Application

Docking Application with TS3DV642 used to switch signals from a single graphic and memory controller to a display port and docking station connector.

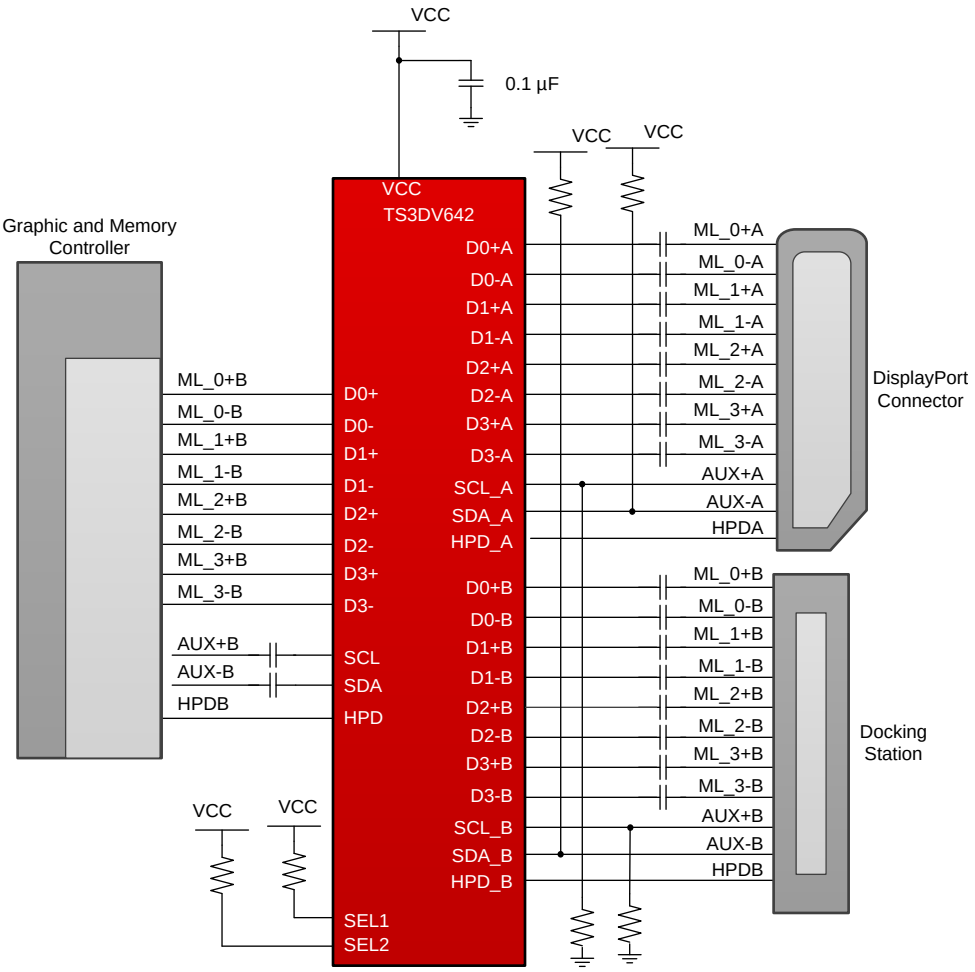


Figure 24. Docking Application Schematic

9.2.2.1 Design Requirements

Table 3. Design parameters for docking application

Design parameter	Example value
V_{CC}	2.6 V to 4.5 V
VCC decoupling capacitor	0.1 µF
MainLink (ML) and AUX coupling capacitor	75 nF to 200 nF
AUX Pull-up / Pull-down resistors	10 kΩ to 100 kΩ
Pull-up / Pull-down resistors for SEL1 / SEL2 pins	10 kΩ

9.2.2.2 Detailed Design Procedure

The TS3DV642 is designed to operate with 2.6 V – 4.5 V power supply. The wide power supply range allows flexibility for battery powered applications. If a higher power supply is used in the system, a voltage regulator can be used to bring down the voltage to 2.6 V – 4.5 V range. Decoupling capacitors may be used to reduce noise and improve power supply integrity. AC coupling capacitors in 75 nF – 200 nF range must be placed on the MainLink (ML) and AUX lanes. In this particular application the AC coupling capacitors are shown on the connector side. The AC coupling capacitors may also be placed on the signal path on controller side. The AUX+ line must be pulled-down weakly through a resistor to ground and the AUX– line must be pulled-up weakly through a resistor to VCC.

9.2.2.3 Application Curves

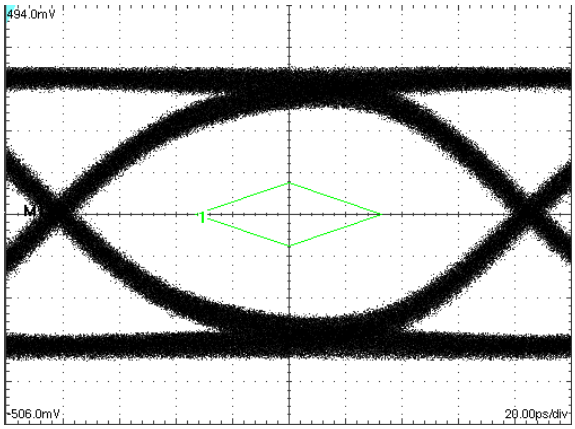


Figure 25. Eye Pattern: 6.0 Gbps Port A, D1+ to D1+A, D1- to D1-A (Only One Channel Measured at a Time)

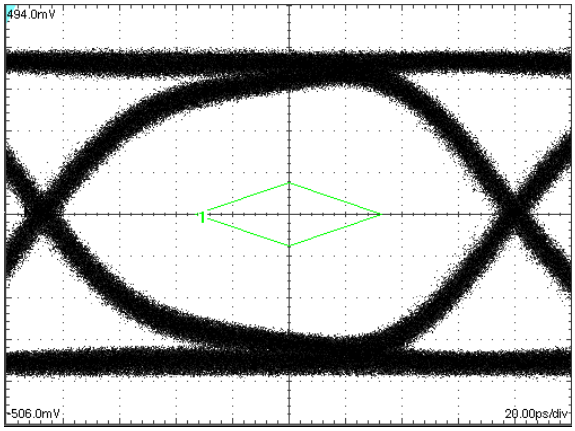


Figure 26. Eye Pattern: 6.0 Gbps, No Device Through Path (Only One Channel Measured at a Time)

9.2.3 HDMI Application

HDMI Application with TS3DV642 used to switch signals from a single graphic and memory controller to a two HDMI connectors.

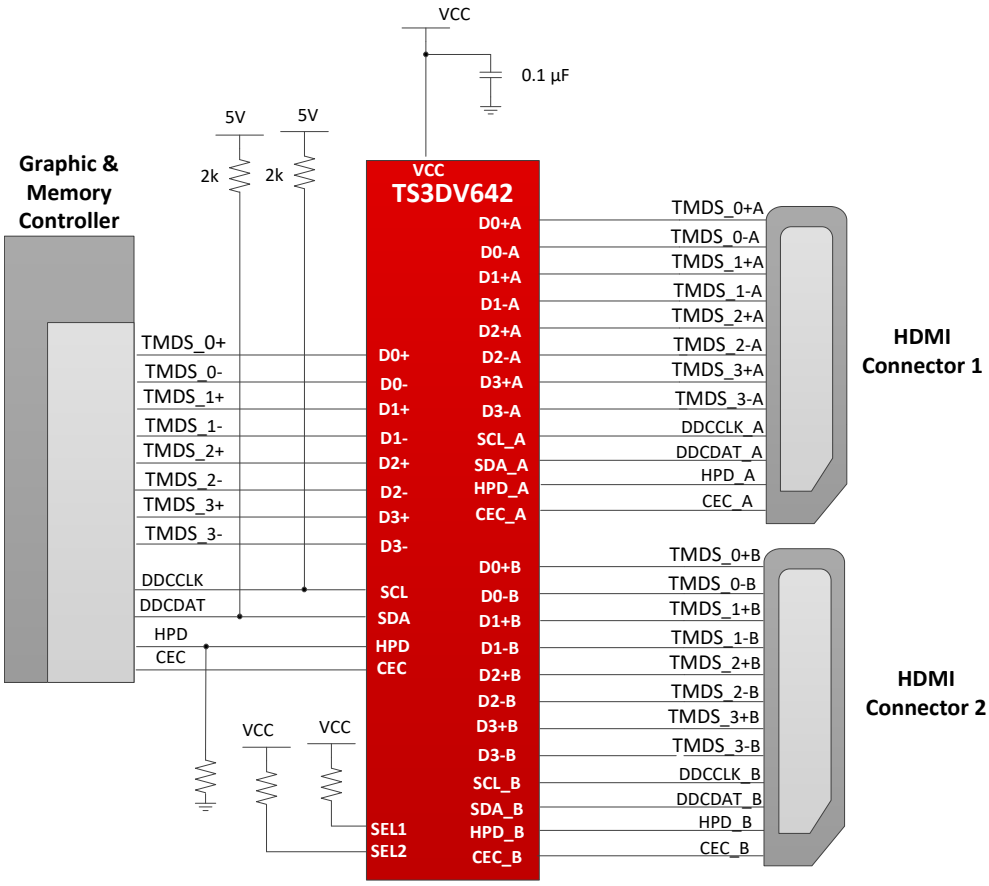


Figure 27. HDMI Application Schematic

9.2.3.1 Design Requirements

Table 4. Design Parameters for HDMI Application

Design parameter	Example value
V_{CC}	2.6 V to 4.5 V
VCC decoupling capacitor	0.1 µF
DDC Pull-up resistors	2 kΩ to 5 V
Pull-up / Pull-down resistors for SEL1 / SEL2 pins	10 kΩ
HPD Pull-down resistor	100 kΩ

9.2.3.2 Detailed Design Procedure

The TS3DV642 is designed to operate with 2.6 V – 4.5 V power supply. The wide power supply range allows flexibility for battery powered applications. If a higher power supply is used in the system, a voltage regulator can be used to bring down the voltage to 2.6 V – 4.5 V range. Decoupling capacitors may be used to reduce noise and improve power supply integrity. Pull-up resistors to 5 V must be placed on the source side DDC clock and data lines according to the HDMI standard. A weak pull-down resistor must be placed on the source side HPD line.

9.2.3.3 Application Curves

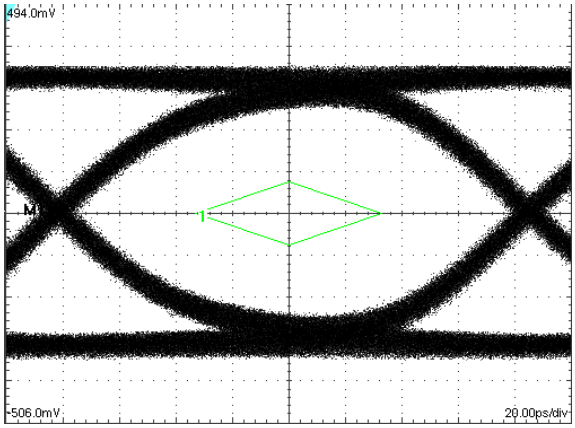


Figure 28. Eye Pattern: 6 Gbps Port A, D1+ to D1+A, D1- to D1-A (Only One Channel Measured at a Time)

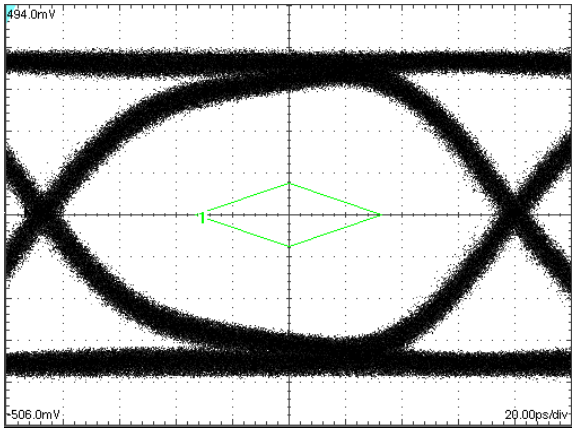


Figure 29. Eye Pattern: 6 Gbps, No Device Through Path (Only One Channel Measured at a Time)

10 Power Supply Recommendations

V_{CC} should be in the range of 2.6 V to 4.5 V. Voltage levels above those listed in the Absolute Ratings table should not be used. Decoupling capacitors may be used to reduce noise and improve power supply integrity. There are no power sequence requirements for the TS3DV642.

11 Layout

11.1 Layout Guidelines

To ensure reliability of the device, the following commonly used printed-circuit board layout guidelines are recommended:

- Decoupling capacitors should be used between power supply pin and ground pin to ensure low impedance to reduce noise To achieve a low impedance over a wide frequency range use capacitors with a high self-resonance frequency.
- ESD and EMI protection devices (if used) should be placed as close as possible to the connector.
- Short trace lengths should be used to avoid excessive loading.
- To minimize the effects of crosstalk on adjacent traces, keep the traces at least two times the trace width apart.
- Separate high-speed signals from low-speed signals and digital from analog signals
- Avoid right-angle bends in a trace and try to route them at least with two 45° corners.
- The high-speed differential signal traces should be routed parallel to each other as much as possible. The traces are recommended to be symmetrical.
- A solid ground plane should be placed next to the high-speed signal layer. This also provides an excellent low-inductance path for the return current flow.

11.2 Layout Example

TS3DV642 application with a single controller interfacing with two HDMI connectors.

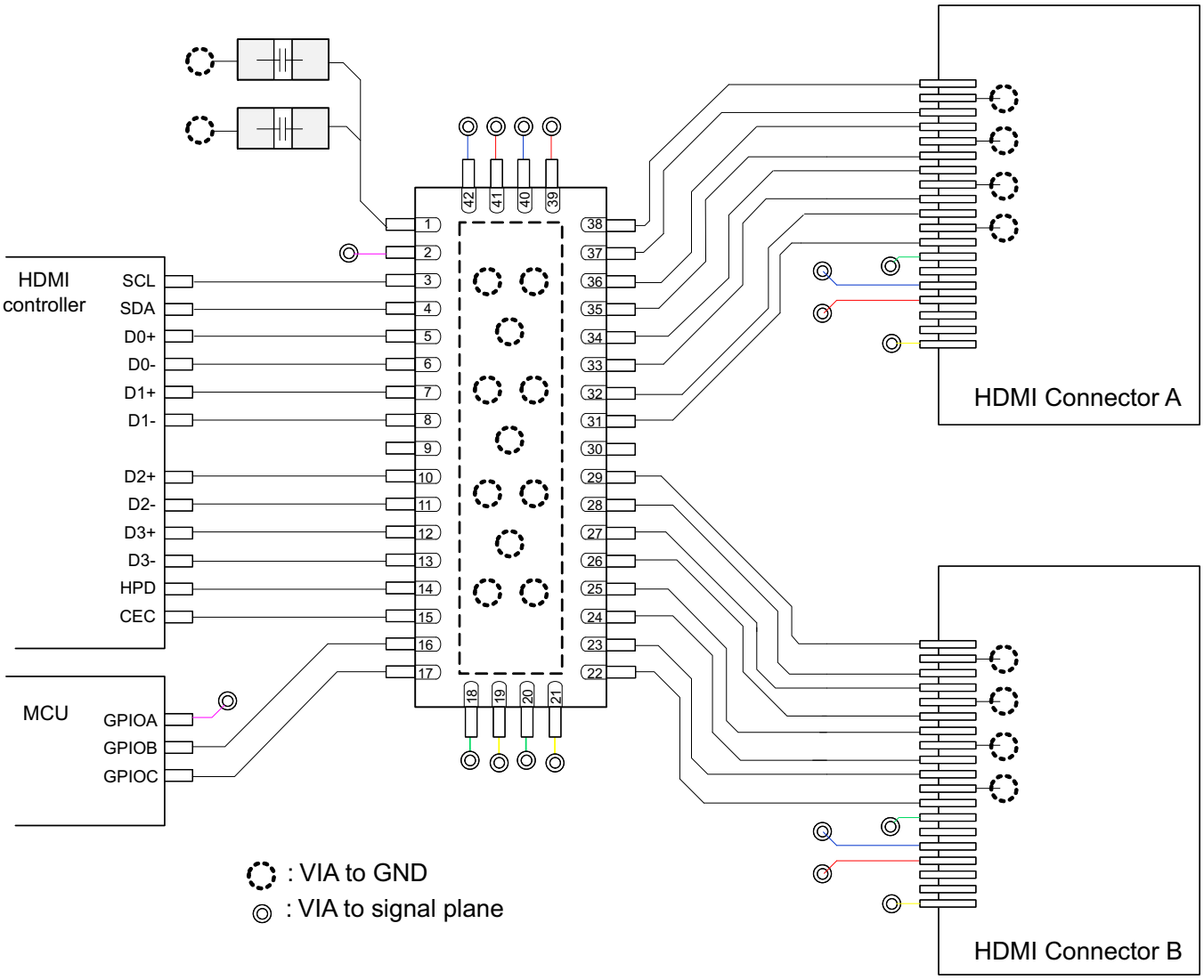


Figure 30. Layout Example

12 デバイスおよびドキュメントのサポート

12.1 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、ti.comのデバイス製品フォルダを開いてください。右上の隅にある「*通知を受け取る*」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

12.2 コミュニティ・リソース

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

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設計サポート ***TIの設計サポート*** **役に立つ**E2E**フォーラムや、設計サポート・ツールをすばやく見つけることができます。技術サポート用の連絡先情報も参照できます。**

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12.5 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 メカニカル、パッケージ、および注文情報

以降のページには、メカニカル、パッケージ、および注文に関する情報が記載されています。この情報は、そのデバイスについて利用可能な最新のデータです。このデータは予告なく変更されることがあり、ドキュメントが改訂される場合もあります。本データシートのブラウザ版を使用されている場合は、画面左側の説明をご覧ください。

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TS3DV642A0RUAR	ACTIVE	WQFN	RUA	42	3000	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 85	SD642A0	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

OTHER QUALIFIED VERSIONS OF TS3DV642 :

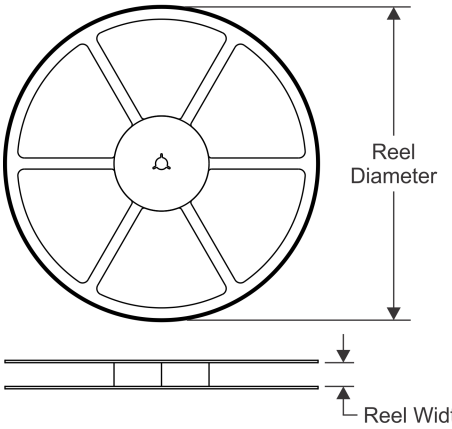
- Automotive : TS3DV642-Q1

NOTE: Qualified Version Definitions:

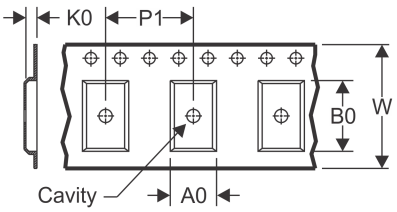
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION

REEL DIMENSIONS

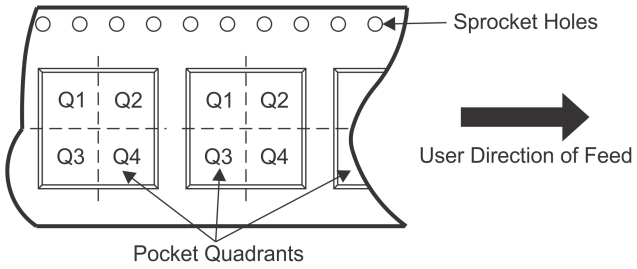


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

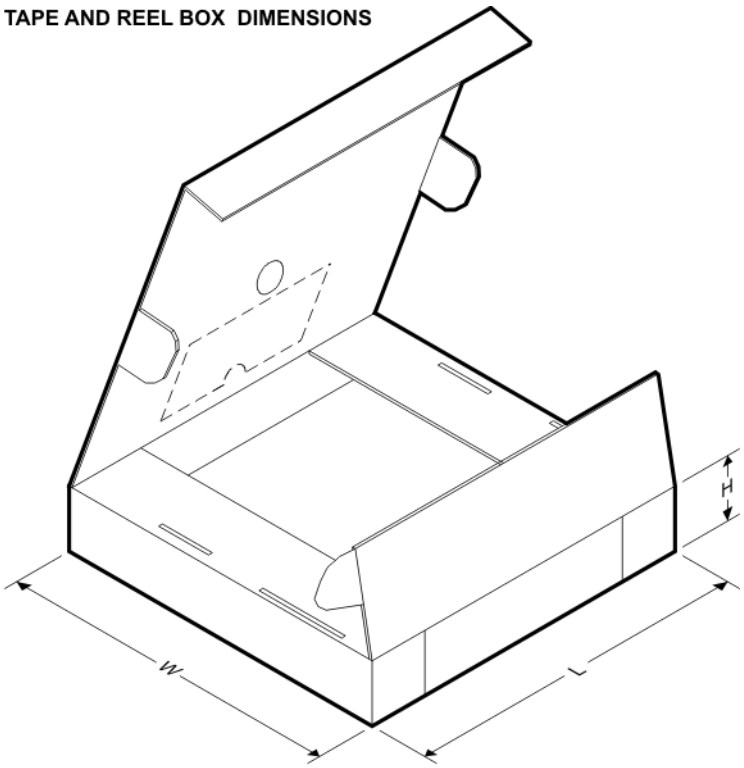
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS3DV642A0RUAR	WQFN	RUA	42	3000	330.0	16.4	3.8	9.3	1.0	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS3DV642A0RUAR	WQFN	RUA	42	3000	367.0	367.0	38.0

GENERIC PACKAGE VIEW

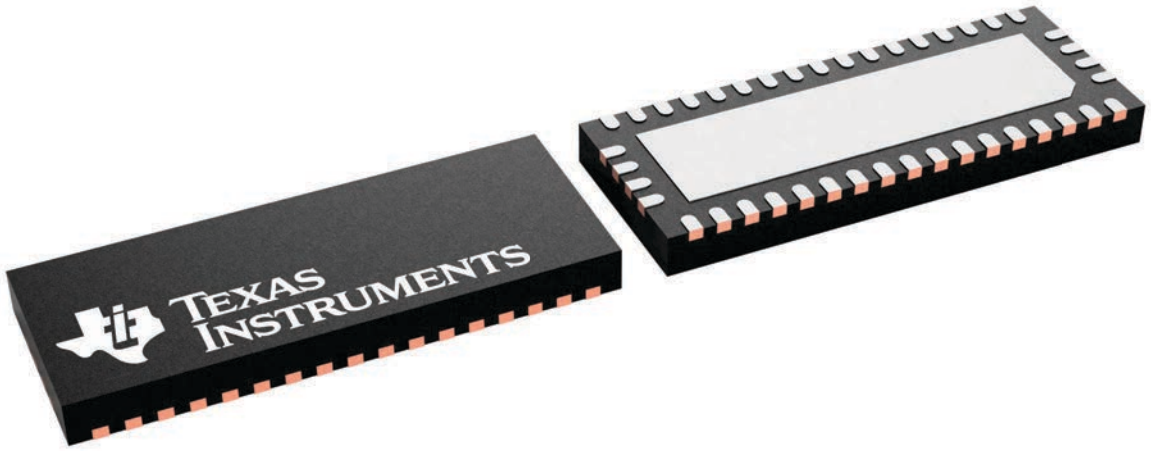
RUA 42

WQFN - 0.8 mm max height

9 x 3.5, 0.5 mm pitch

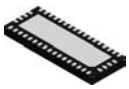
PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



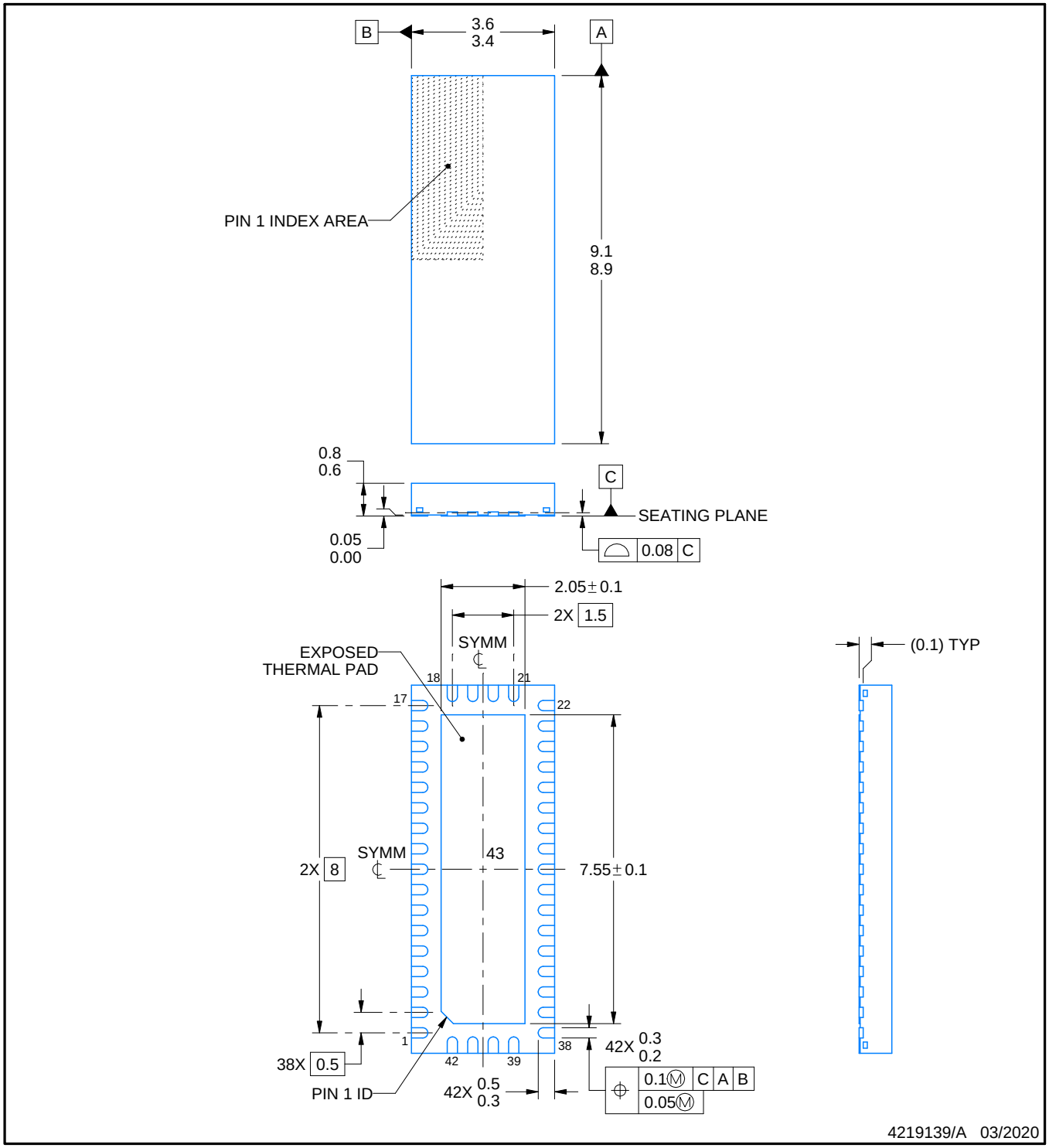
PACKAGE OUTLINE

RUA0042A



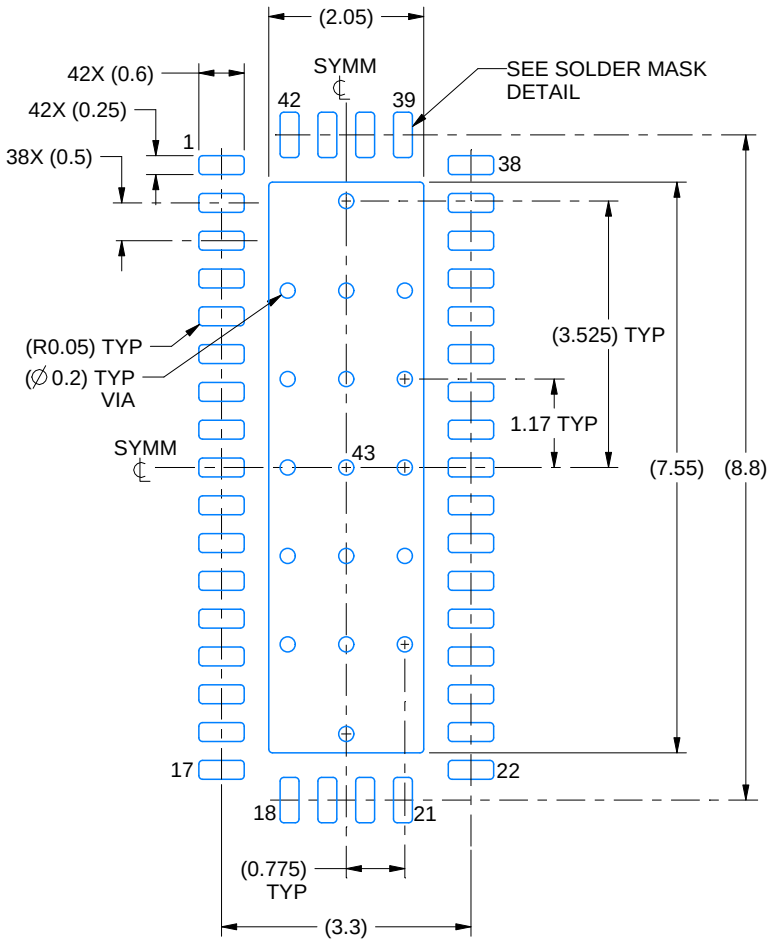
WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

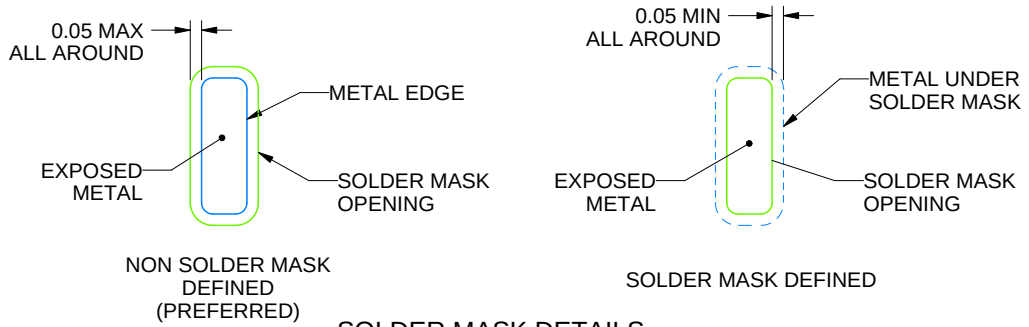


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

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NOTES: (continued)

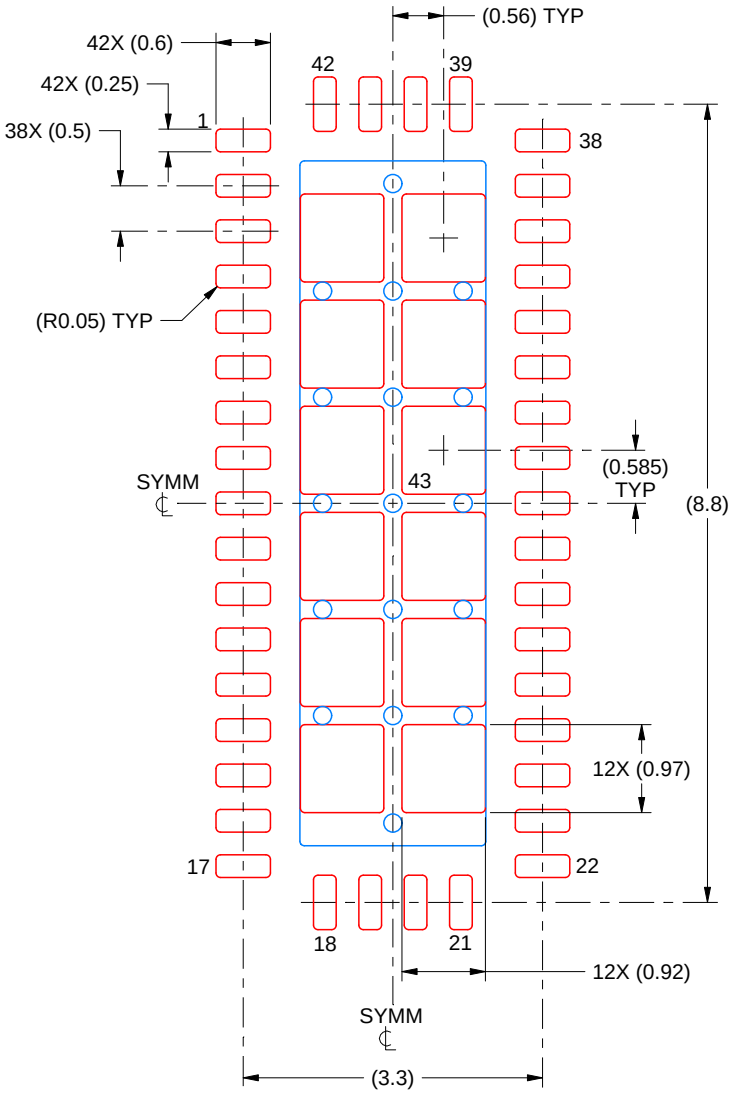
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RUA0042A

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 MM THICK STENCIL
SCALE: 12X

EXPOSED PAD 43
69% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE

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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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